Metal Can® TO56

Green Laser Diode in TO56 Package









Applications

- Architecture / Garden Lighting (LED & Laser)
- Area Lights
- Downlights/Spotlights

- Mood Lighting
- Street, Tunnel and Outdoor

Features:

- Optical output power (continuous wave): 20 mW ($T_c = 25$ °C)
- Typical emission wavelength: 520 nm
- Efficient radiation source for cw and pulsed operation
- Single mode semiconductor laser
- High modulation bandwidth
- TO56 package with photo diode

Ordering Information

Type	Peak output power	Ordering Code
	typ.	
	P_{opt}	
PLT5 520EA_P	20 mW	Q65112A7750



Maximum Ratings

 $T_{\rm C}$ = 25 °C

Parameter	Symbol		Values
Operating temperature	T_{op}	min.	-20 °C
	op.	max.	60 °C
Storage temperature	T _{stg}	min.	-40 °C
	3.9	max.	85 °C
Junction temperature	T_{j}	max.	120 °C
Forward current 1)	I _F	max.	200 mA
Reverse voltage 2)	V_{R}	max.	2 V
Soldering temperature	T _s	max.	260 °C
t _{max} = 10 s			

Operation outside these conditions may damage the device. Operation at maximum ratings may influence lifetime.



Characteristics

P _{opt} =	20	mW;	T	=	25	$^{\circ}C$
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Parameter	Symbol		Values
Operating current 1) B1 - B3	I _{op}	typ. max.	58 mA 62 mA
Operating current 1) B4 - B6	l _{op}	typ. max.	65 mA 82 mA
Operating voltage 3)	V_{op}	typ. max.	5.5 V 6.3 V
Peak wavelength 4)	λ_{peak}	min. typ. max.	510 nm 520 nm 530 nm
Spectral bandwidth (FWHM)	Δλ	typ.	2 nm
Beam divergence (FWHM) parallel to pn-junction	Θ_{\parallel}	min. typ. max.	6 ° 8 ° 10 °
Beam divergence (FWHM) perpendicular to pn-junction	Θ_{\perp}	min. typ. max.	19 ° 22 ° 25 °
Threshold current	I _{th}	typ. max.	30 mA 50 mA
TE polarization	P_{TE}	typ.	100:1
Modulation frequency	f	min.	100 MHz
Monitor current ⁵⁾⁶⁾ V _R = 5 V	I _m	typ.	25 μΑ
Thermal resistance junction case real	R_{thJC}	typ.	34 K / W

Info: according to OS-IN-2020-036



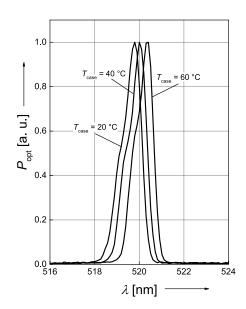
Wavelength Groups

 I_{opt} <= 62 mA: B1 - B3; I_{opt} = 62 mA - 82 mA: B4 - B6

Group	Peak wavelength 7)	Peak wavelength 7)	
	min.	max.	
	$\lambda_{\sf peak}$	$\lambda_{\sf peak}$	
B1	510 nm	515 nm	
B4	510 nm	515 nm	
B2	515 nm	520 nm	
B5	515 nm	520 nm	
B3	520 nm	530 nm	
B6	520 nm	530 nm	

Relative Spectral Emission 8), 9)

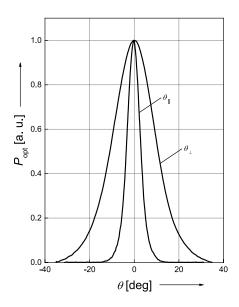
 $I_{e,rel} = f(\lambda); I_F = 65 \text{ mA}; P_{opt} = 20 \text{ mW}$





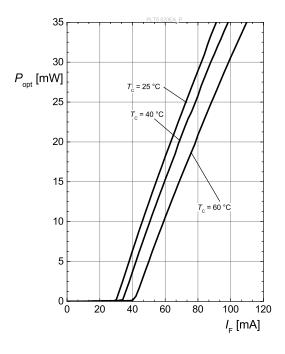
Beam Divergence 8), 9)

$$P_{opt} = f(\Theta)$$



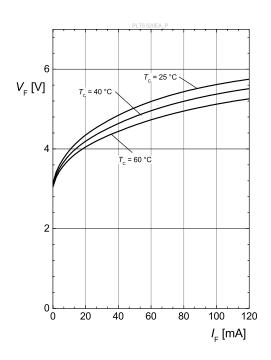
Optical Output Power 8), 9)

$$P_{opt} = f(I_F)$$



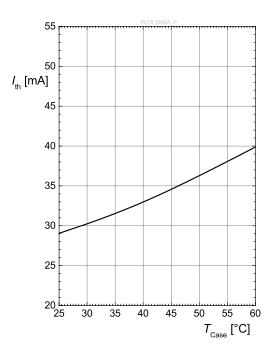
Opt. Power / Forward Voltage 8), 9)

$$V_F = f(I_F)$$



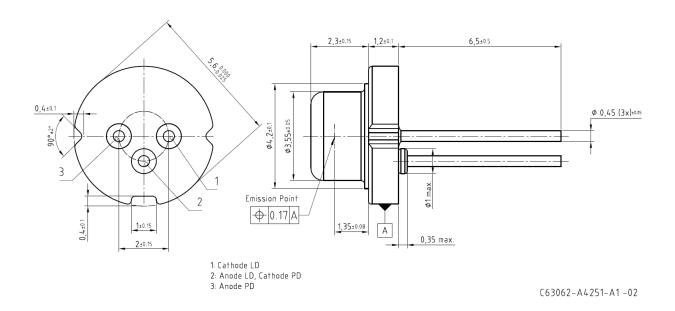
Threshold Current

$$I_{th} = f(T_{C})$$





Dimensional Drawing 10)



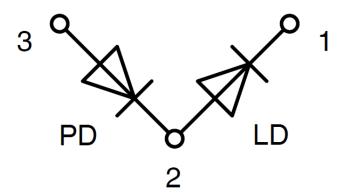
Further Information:

Approximate Weight: 310.0 mg

ESD advice: ATTENTION – Observe Precautions For Handling – Electrostatic Sensitive

Device

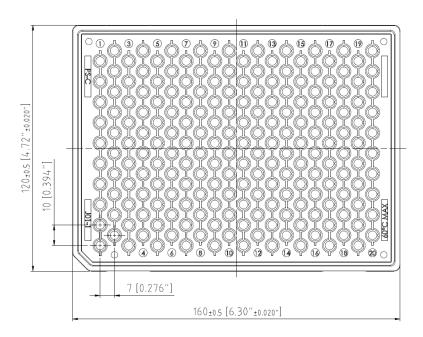
Electrical Internal Circuit



Pin	Description
PIN1	LD Cathode
PIN 2	LD Anode, PD Cathode (case)
PIN 3	PD Anode

Tray 10)

200 pieces per Tray



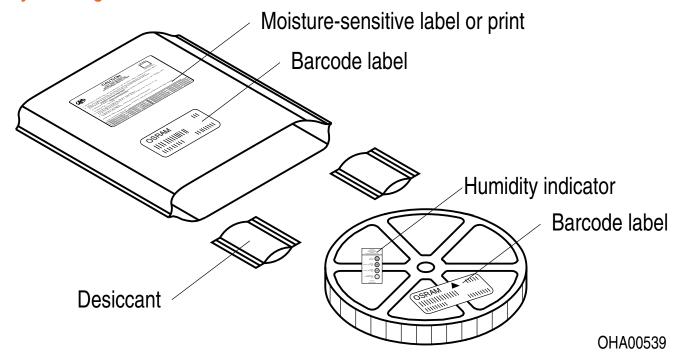
C63062-A4337-B1

Barcode-Product-Label (BPL)

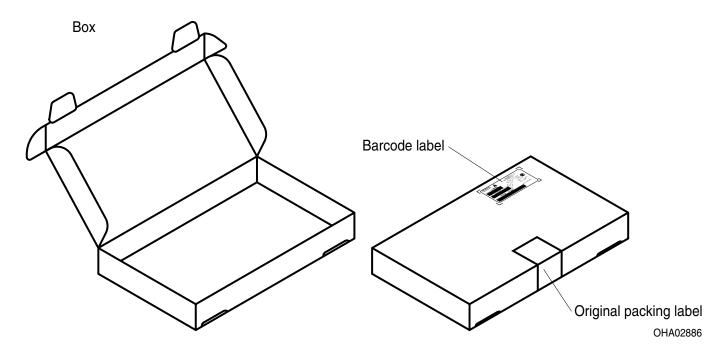




Dry Packing Process and Materials



Schematic Transportation Box 10)



Dimensions of Transportation Box

Width	Length	Height
215 ± 5 mm	265 ± 5 mm	95 ± 5 mm



Notes

Depending on the mode of operation, these devices emit highly concentrated visible and non visible light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.



Glossary

- Operating/Forward current: IF is measured with an internal reproducibility of ± 7 % (acc. to GUM with a coverage factor of k = 3).
- Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- Operating/Forward voltage: VF is measured with an internal reproducibility of ± 0.05 V (acc. to GUM with a coverage factor of k = 3).
- Wavelength: λ peak is measured with an internal reproducibility of ±0.3 nm (acc. to GUM with a coverage factor of k = 3).
- Monitor current: Monitor current refers to a reverse voltage of VRPD = 5 V. Monitor current is for short time power reference purpose only. Not guaranteed for accuracy.
- 6) **Monitor current:** For reference only.
- Wavelength: The wavelengths are measured with a tolerance of ±1 nm.
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- ⁹⁾ **Testing temperature:** TA = 25°C (unless otherwise specified)
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.



Revision History			
Version	Date	Change	
1.1	2019-06-07	Initial Version	
1.2	2020-05-13	Characteristics	
1.3	2020-05-18	Characteristics Electro - Optical Characteristics (Diagrams)	
1.4	2020-12-08	Characteristics Wavelength Groups	



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